

Name :

Roll No. :

Invigilator's Signature :

CS/B.Tech(N)/SEM-1/ES-101/2012-13

2012

**BASIC ELECTRICAL &
ELECTRONICS ENGINEERING – I**

Time Allotted : 3 Hours

Full Marks : 70

**THIS QUESTION BOOKLET CONSISTS OF 2 PARTS —
PART I & PART II.
TO ANSWER THE QUESTIONS USE SEPARATE ANSWER
BOOKS FOR SEPARATE PARTS.
DO NOT ANSWER BOTH THE PARTS IN THE SAME
ANSWER-BOOK.**

The figures in the margin indicate full marks.

*Candidates are required to give their answers in their own words
as far as practicable.*

PART – I

(Marks : 35)

GROUP – A

(Multiple Choice Type Questions)

1. Choose the correct alternatives for any *five* of the following :

5 × 1 = 5

i) Conductance is analogous to

a) permeance

b) flux

c) reluctance

d) inductance.

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ii) Energy stored by a capacitor is given by

a) $\frac{1}{2} CV^2$

b) $\frac{1}{2} QV$

c) $\frac{Q^2}{2C}$

iii) In an electrical circuit, if the current lags the voltage by 60° , the circuit nature is

a) R-C

b) R-L

c) LC

d) none of these.

iv) Kirchoff's voltage law is used for

a) loop analysis

b) node analysis

c) finding out equivalent resistance

d) none of these.

v) If $E_1 = A \sin \omega t$ and $E_2 = A \sin (\omega t - \theta)$, then

a) E_1 lags E_2

b) E_2 lags E_1

c) E_1 and E_2 are in phase

d) none of these.

vi) The bandwidth of a series resonant a.c. circuit is equal to

a) $\frac{R}{2\pi L}$

b) $\frac{1}{(RLC)}$

c) $\frac{1}{(2\pi R)}$

d) $\frac{1}{(\omega C)}$

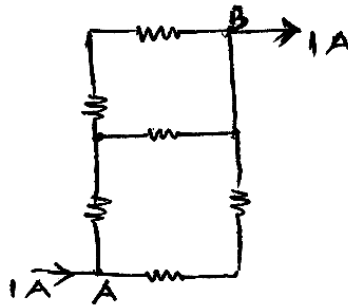


GROUP – B

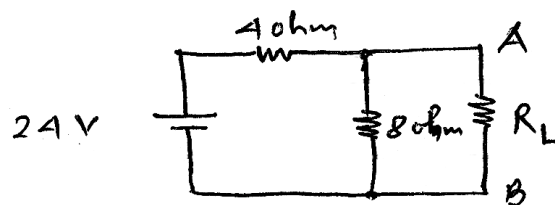
(Short Answer Type Questions)

Answer any *two* of the following. $2 \times 5 = 10$

2. Derive an expression for the resonant frequency of a parallel circuit, one branch consisting of a coil of inductance L and a resistance R and the other branch of capacitance C .
3. Establish the equivalence between Thevenin's and Norton's theorems.
4. Find V_{AB} from the circuit if all the resistances are of same value of 1 ohm.



5. Find the value of load resistance (R_L) for which the power source will supply maximum power. Also find the value of the maximum power for the network as shown below :





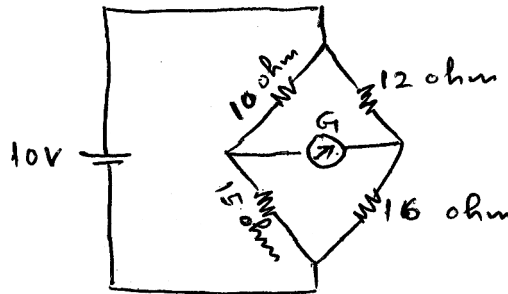
GROUP - C

(Long Answer Type Questions)

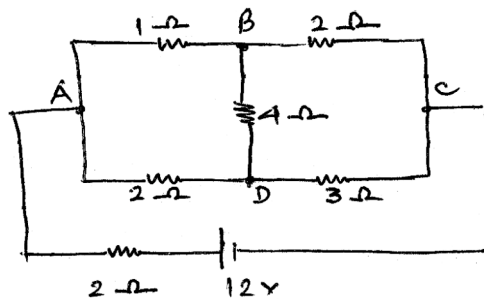
Answer any *two* of the following.

$2 \times 10 = 20$

6. a) Define power factor of an A.C. circuit. State the disadvantages associated with having a load power factor. 4
- b) The galvanometer shown in the circuit has a resistance of 5 ohms. Find the current through the galvanometer using Thevenin's theorem.



7. a) Find the current in each branch of the network using Kirchhoff's law. 5



- b) Prove that the current in a purely resistive circuit is in phase with applied A.C. voltage and current in a purely capacitive circuit leads applied voltage by 90° and also draw their waveforms. 5



8. a) Define self and mutual inductance. Derive an expression for coefficient of coupling (k) involving self inductances L_1 & L_2 and mutual inductance M . 4
- b) What is meant by hysteresis in a magnetic circuit ? What is the significance of B-H curve ? 3
- c) Find an expression for the energy stored in a magnetic field. 3
9. Explain (a) Star-delta conversion, (b) delta-star conversion with the help of a purely resistive circuit. 5 + 5

USE SEPARATE ANSWER-BOOK TO ANSWER PART-II QUESTIONS.

PART – II

(Marks : 35)

GROUP – A

(Multiple Choice Type Questions)

1. Choose the correct alternatives for any *five* of the following :
- $5 \times 1 = 5$
- i) A transistor having a high input impedance and a low output impedance is operating in
- a) *CB* mode b) *CE* mode
- c) *CC* mode d) inverted mode.



- ii) α and β of a transistor are related by
- a) $\alpha = (\beta + 1) / \beta$ b) $\beta = \alpha / (1 - \alpha)$
c) $\beta = \alpha / (1 + \alpha)$ d) $\alpha = \beta / (1 - \beta)$.
- iii) The ripple factor of a half wave rectifier is
- a) 0.482 b) 0.41
c) 1.21 d) 1.11
- iv) When both junctions are reverse biased, a transistor operates in
- a) active b) saturation
c) cut-off d) inverted region.
- v) Band gap of Ge is
- a) 0.54 eV b) 1.1 eV
c) 0.72 eV d) none of these.
- vi) An n -type semiconductor is
- a) negatively charged
b) positively charged
c) neutral.

GROUP – B

(Short Answer Type Questions)

Answer any *two* of the following. $2 \times 5 = 10$

2. Explain the operation of a full wave rectifier with centre tapped transformer and draw the D.C. output waveform.
3. What is the role of doping of impurities in pure silicon or germanium ? Draw roughly the position of Fermi level for extrinsic semiconductor and explain.



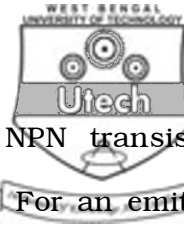
4. Write a short note on varactor diode.
5. At 300 K, the intrinsic carrier concentration of silicon is $1.5 \times 10^{16} \text{ m}^{-3}$. If the electron and hole mobilities are 0.13 and 0.05 $\text{m}^2\text{V}^{-1}\text{s}^{-1}$, calculate the intrinsic resistivity of Si at 300 K.

GROUP – C

(Long Answer Type Questions)

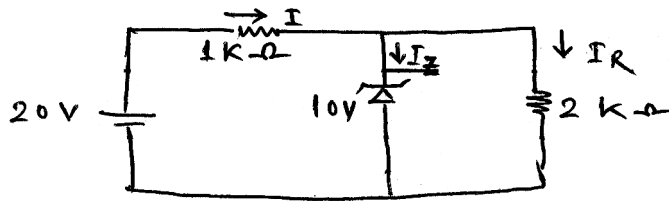
Answer any *two* of the following. $2 \times 10 = 20$

6. a) Write the differences between Zener breakdown and avalanche breakdown. 3
b) Explain how a Zener diode can act as a voltage regulator. 4
c) Write a short note on clipper circuit. 3
7. a) Discuss the static characteristics of transistor in CB configuration. 5
b) What do you mean by intrinsic semiconductor ? Explain drift and diffusion current for a semiconductor . 2 + 3



8. a) The reverse saturation current of a NPN transistor operating in CB configuration is $10 \mu\text{A}$. For an emitter current of 2.4 mA , the collector current is 2.26 mA . Calculate the current gain and base current. 5

b) Calculate the current I , I_R and I_Z for the following circuit. 5



9. Write short notes on any *two* of the following : 2 × 5

- a) Clamper circuit
- b) Fermi level
- c) Junction capacitance.

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